

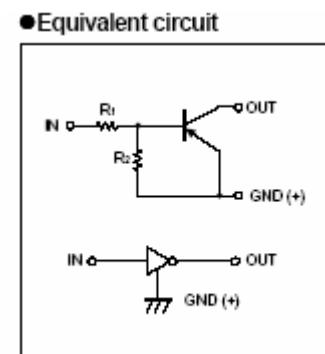


## Digital transistors (built-in resistors)

**DTA144EE/DTA144EUA**

**DTA144ECA /DTA144EKA/DTA144ESA**

DIGITAL TRANSISTOR (PNP)



### FEATURES

1. Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see equivalent circuit)
2. The bias resistors consist of thin-film resistors with complete isolation to allow positive biasing of the input. They also have the advantage of almost completely eliminating parasitic effects
3. Only the on/off conditions need to be set for operation, making device design easy

### PIN CONNECTIONS AND MARKING

<b>DTA144EE</b>		<b>DTA144EUA</b>	
SOT-523	Addreviated symbol: 16	SOT-323	Addreviated symbol: 16
<b>DTA144EKA</b>		<b>DTA144ECA</b>	
SOT-23-3L	Addreviated symbol: 16	SOT-23	Addreviated symbol: 16
<b>DTA144ESA</b>			
TO-92S			

### Absolute maximum ratings(Ta=25°C)

Parameter	Symbol	Limits (DTA144E□ )					Unit				
		E	UA	KA	CA	SA					
Supply voltage	V <sub>CC</sub>	-50					V				
Input voltage	V <sub>IN</sub>	-40~+10					V				
Output current	I <sub>O</sub>	-30					mA				
	I <sub>C(MAX)</sub>	-100									
Power dissipation	P <sub>d</sub>	150	200		300		mW				
Junction temperature	T <sub>j</sub>	150					°C				
Storage temperature	T <sub>stg</sub>	-55~150					°C				

### Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min	Typ	Max	Unit	Conditions
Input voltage	V <sub>I(off)</sub>	-0.5			V	V <sub>CC</sub> =-5V ,I <sub>O</sub> =-100μA
	V <sub>I(on)</sub>			-3		V <sub>O</sub> =-0.3V ,I <sub>O</sub> =-2mA
Output voltage	V <sub>O(on)</sub>			-0.3	V	I <sub>O</sub> /I <sub>I</sub> =-10mA/-0.5mA
Input current	I <sub>I</sub>			-0.18	mA	V <sub>I</sub> =-5V
Output current	I <sub>O(off)</sub>			-0.5	μA	V <sub>CC</sub> =-50V ,V <sub>I</sub> =0
DC current gain	G <sub>I</sub>	68				V <sub>O</sub> =-5V ,I <sub>O</sub> =-5mA
Input resistance	R <sub>1</sub>	32.9	47	61.1	KΩ	
Resistance ratio	R <sub>2</sub> /R <sub>1</sub>	0.8	1	1.2		
Transition frequency	f <sub>T</sub>		250		MHz	V <sub>O</sub> =-10V ,I <sub>O</sub> =-5mA,f=100MHz